



FZT955

June 2018 © Diodes Incorporated

140V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > -140V
- I_C = -4A High Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -150mV @ -1A
- h_{FE} Specified up to -10A for a High Gain Hold-up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

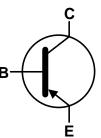
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.112 grams (Approximate)

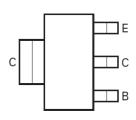




Top View



Device Symbol



Top View Pin-Out

Ordering Information (Notes 4)

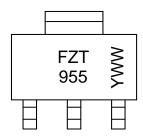
Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT955TA	FZT955	7	12	1000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, see http://www.diodes.com/products/packages.html.

Marking Information

SOT223



FZT 955 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-180	V
Collector-Emitter Voltage	$V_{\sf CEO}$	-140	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	lc	-4	Α
Peak Pulse Current	Ісм	-10	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)		3.0 24	W
Linear Derating Factor	(Note 6)	P _D	1.6 12.8	mW /°C
Thermal Desistance Junction to Ambient	(Note 5)	R _{OJA}	42	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\Theta JA}$	78	°C/W
Thermal Resistance Junction to Lead	(Note 7)	$R_{\Theta JL}$	8.84	
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 8)

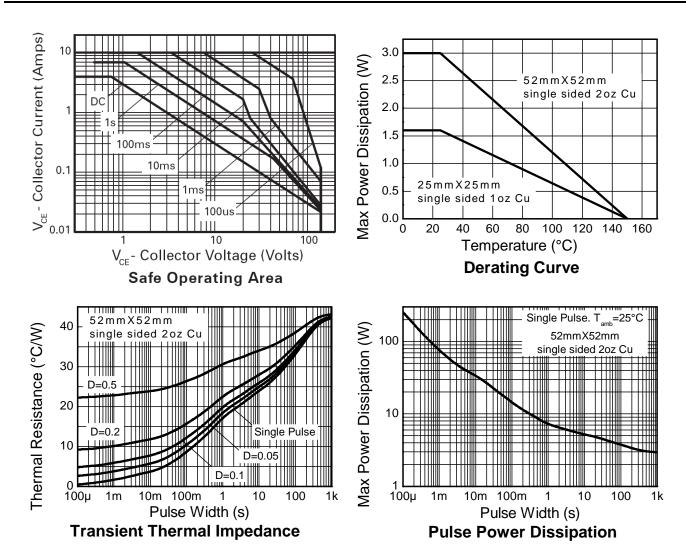
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4,000	V	3B
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector lead on 52mm × 52mm 2oz copper on a single-sided 1.6mm FR4 PCB; the device is measured under still air conditions whilst operating in steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Electrical Characteristics ($@T_A = +25$ °C, unless otherwise specified.)

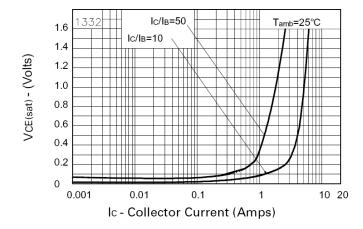
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	-180	-210	I	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage	BV_CER	-180	-210	-	V	$I_C = -1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-140	-170	1	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8	-	V	$I_E = -100 \mu A$
Collector Cut-Off Current	I _{CBO}		<1 —	-50 -1	nA μA	V _{CB} = -150V V _{CB} = -150V, T _A = +100°C
Collector Cut-Off Current	I _{CER} R≤1kΩ	_	<1 —	-50 -1	nA μA	V _{CE} = -150V V _{CE} = -150V, T _A = +100°C
Emitter Cut-Off Current	I _{EBO}		_	-10	nA	V _{EB} = -6V
		100	200	_		$I_C = -10 \text{mA}, V_{CE} = -5 \text{V}$
DC Current Transfer Static Ratio (Note 0)		100	200	300	_	I _C = -1A, V _{CE} = -5V
DC Current Transfer Static Ratio (Note 9)	h _{FE}	75	140	_		$I_C = -3A$, $V_{CE} = -5V$
		_	10	_		$I_C = -10A$, $V_{CE} = -5V$
	V _{CE} (sat)	_	-30	-60	mV	$I_C = -100 \text{mA}, I_B = -5 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)		ı	-70	-120		$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Collector-Emiller Saturation Voltage (Note 9)		_	-110	-150		$I_C = -1A$, $I_B = -100mA$
		I	-275	-370		$I_C = -3A$, $I_B = -300mA$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	I	-970	-1,110	mV	$I_C = -3A$, $I_B = -300mA$
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	I	-830	-950	mV	$I_C = -3A$, $V_{CE} = -5V$
Transitional Frequency (Note 9)	f _T	_	110	_	MHz	I _C = -100mA, V _{CE} = -10V, f = 50MHz
Output Capacitance	C _{obo}	_	40	_	pF	V _{CB} = -20V, f = 1MHz
Switching Time	t _{ON}	_	68	_	no	V _{CC} = -50V, I _C = -1A,
Switching Time	t _{OFF}	_	1,030	_	ns	$-I_{B1} = I_{B2} = -100 \text{mA}$

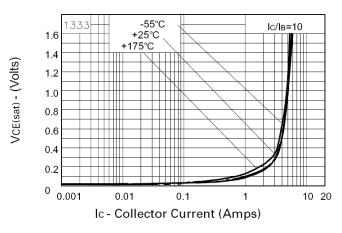
Note:

9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

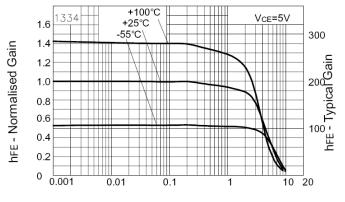


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

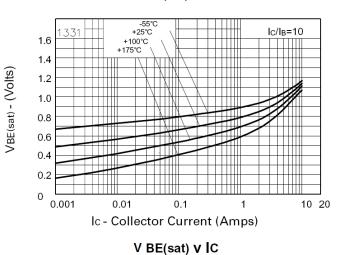




VCE(sat) v IC

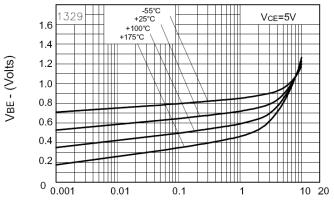


VCE(sat) v IC



Ic - Collector Current (Amps)

hFE v IC



Ic - Collector Current (Amps)

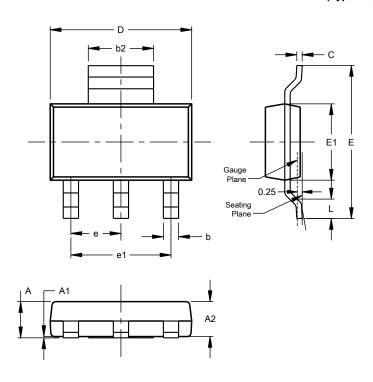
VBE(on) v IC



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

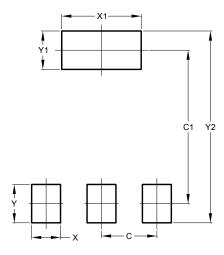


SOT223 (Type DN)				
Dim	Min	Max	Тур	
Α	_	1.70	_	
A1	0.01	0.15		
A2	1.50	1.68	1.60	
b	0.60	0.80	0.70	
b2	2.90	3.10		
С	0.20	0.32	_	
D	6.30	6.70		
Е	6.70	7.30	_	
E1	3.30	3.70		
е	_	_	2.30	
e1	_	_	4.60	
L	0.85	_	_	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)		
С	2.30		
C1	6.40		
Х	1.20		
X1	3.30		
Υ	1.60		
Y1	1.60		
Y2	8.00		



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